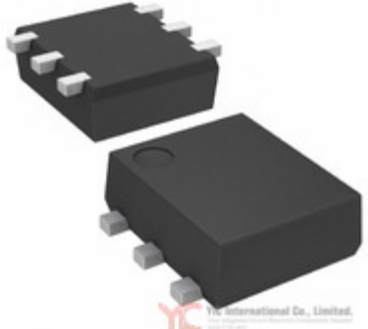





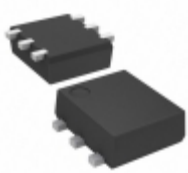

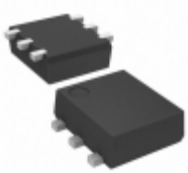

	VT6M1T2CR	
	Hersteller-Teilenummer:	VT6M1T2CR
	Hersteller / Marke:	LAPIS Semiconductor
	Teil der Beschreibung:	MOSFET N/P-CH 20V 0.1A VMT6
	Datenblätter:	 VT6M1T2CR.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 26673 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	VT6M1T2CR
Hersteller	LAPIS Semiconductor
Beschreibung	MOSFET N/P-CH 20V 0.1A VMT6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	26673 pcs Stock
Serie	-
Betriebstemperatur	150 °C (TJ)
Befestigungsart	Surface Mount
Leistung - max	120mW
Verpackung / Gehäuse	6-SMD, Flat Leads
Supplier Device-Gehäuse	VMT6
Typ FET	N and P-Channel
FET-Merkmal	Logic Level Gate, 1.2V Drive
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	100mA
Rds On (Max) @ Id, Vgs	3.5 Ohm @ 100mA, 4.5V
VGS (th) (Max) @ Id	1V @ 100µA
Gate Charge (Qg) (Max) @ Vgs	-
Eingabekapazität (Ciss) (Max) @ Vds	7.1pF @ 10V
Verpackung	Tape & Reel (TR)


























VT6M1T2CR ist neu im Original, Suche VT6M1T2CR Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie VT6M1T2CR LAPIS Semiconductor mit Garantie und Vertrauen.
Anfrage VT6M1T2CR: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>VT6T11T2R ROHM ROHM VMT6</p>	 <p>VT6X1 T2R LAPIS Semiconductor VT6X1 T2R ROHM</p>	 <p>VT6M1 FU7T2CR LAPIS Semiconductor VT6M1 FU7T2CR ROHM</p>	 <p>VT6T12 T2R ROHM ROHM SMD</p>
 <p>VT6K1T2CR LAPIS Semiconductor MOSFET 2N-CH 20V 0.1A VMT6</p>	 <p>VT6X1 LAPIS Semiconductor VT6X1 ROHM</p>	 <p>VT6J1T2CR LAPIS Semiconductor MOSFET 2P-CH 20V 0.1A VMT6</p>	 <p>VT6M1 LAPIS Semiconductor VT6M1 ROHM</p>

heiße Teile

Mehr

 06031C561K4T2A	 06033A101JAT9A	 5STP34Q5200	 AD8605ACB-REEL7	 ADA4424-6ARUZ
 ADG888BCBZ-REEL	 AT88SC0808C-SU	 B59008C110A40	 BCM4100KTE	 BT138-800E
 BTA204W-600B	 C2012X7R1E105K085AB	 C2012X8R2A473K125AB	 CAT25C16V-TE13	 CC0603GRNPO9BN471
 CC2541F256RHAT	 CD74HCT174M	 CL31C102FBCNNNL	 CRCW201020R0JNEF	 DP20K600T101627
 FIN212ACMLX	 GRM0225C1E6R2WA03L	 GRM033R71H151MA12J	 GRM219R60J106KE19D	 HOP600-SB
 IRF7470TRPBF	 IRU3146CFTR	 ISL95836HRTZ-T	 LD061C471KAB2A	 LMX3161VBHX
 LPC11U14FBD48/201	 LT1712CGN#PBF	 LT3513IUHF#TRPBF	 MAX8862RESE	 MAZ8043GHL
 MC10EP17DWR2G	 MCD250-12I01	 MT48LC2M8A1TG-8BS	 MX7545KCWP+T	 OKI-78SR-3.3/1.5-W36-C
 P0080SAMCRP	 R1279NS25L	 SPX29152T5	 SSA500AA160	 STP45NF03L
 TDA3606T	 TL2842BP	 UND-50PW/25	 VT6K1T2CR	 VT6X1T2R

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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